PHE13009

#### **GENERAL DESCRIPTION**

The PHE13009 is a silicon npn power switching transistor in the TO220AB envelope intended for use in high frequency electronic lighting ballast applications, converters, inverters, switching regulators, motor control systems, etc.

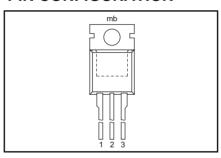
### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>CESM</sub>	Collector-emitter voltage peak value	$V_{BF} = 0 \text{ V}$	-	700	V
V <sub>CBO</sub>	Collector-Base voltage (open emitter)		-	700	V
V <sub>CEO</sub>	Collector-emitter voltage (open base)		-	400	V
I <sub>C</sub>	Collector current (DC)		-	12	Α
I <sub>CM</sub>	Collector current peak value		-	24	Α
P <sub>tot</sub>	Total power dissipation	$T_{mb} \le 25  ^{\circ}C$	-	80	W
V <sub>CEsat</sub>	Collector-emitter saturation voltage	$I_{\rm C} = 5.0  \text{A}; I_{\rm B} = 1.0  \text{A}$	0.32	1.0	V
h <sub>FEsat</sub>		$I_{\rm C} = 5.0 \text{ A}; V_{\rm CF} = 5 \text{ V}$	-	40	
t <sub>f</sub>	Fall time	$I_{\rm C} = 5.0 \text{ A}; I_{\rm B1} = 1.0 \text{ A}$	0.1	0.5	μs

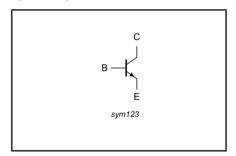
#### **PINNING - TO220AB**

PIN	DESCRIPTION			
1	base			
2	collector			
3	emitter			
tab	collector			

#### **PIN CONFIGURATION**



#### **SYMBOL**



### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CESM</sub>	Collector to emitter voltage	$V_{BE} = 0 V$	-	700	V
$V_{CEO}$	Collector to emitter voltage (open base)		-	400	V
$V_{CBO}$	Collector to base voltage (open emitter)		-	700	V
l <sub>C</sub>	Collector current (DC)		-	12	Α
I I <sub>CM</sub>	Collector current peak value		-	24	Α
I <sub>B</sub>	Base current (DC)		-	6	Α
l I <sub>BM</sub>	Base current peak value		-	12	Α
P <sub>tot</sub>	Total power dissipation	T <sub>mb</sub> ≤ 25 °C	-	80	W
T <sub>stq</sub>	Storage temperature	THE	-65	150	°C
$T_{j}^{s,g}$	Junction temperature		-	150	°C

# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Junction to mounting base		-	1.56	K/W
R <sub>th j-a</sub>	Junction to ambient	in free air	60	-	K/W

WeEn Semiconductors Product data sheet

# Silicon Diffused Power Transistor

PHE13009

## STATIC CHARACTERISTICS

 $T_{mb}$  = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CES</sub> ,I <sub>CBO</sub>	Collector cut-off current <sup>1</sup>		-	-	1.0 5.0	mA mA
I <sub>CEO</sub> I <sub>EBO</sub> V <sub>CEOsust</sub> V <sub>CEsat</sub>	Collector cut-off current Emitter cut-off current Collector-emitter sustaining voltage Collector-emitter saturation voltage	$\begin{aligned} &V_{\text{CEO}} = V_{\text{CEOMmax}}  (400 \text{V}) \\ &V_{\text{EB}} = 9  \text{V};  I_{\text{C}} = 0  \text{A} \\ &I_{\text{B}} = 0  \text{A};  I_{\text{C}} = 10  \text{mA}; \\ &L = 25  \text{mH} \\ &I_{\text{C}} = 5.0  \text{A}; I_{\text{B}} = 1.0  \text{A} \end{aligned}$	- - 400	- - - 0.32	0.1 1 - 1.0	mA mA V
V CEsat V <sub>BEsat</sub>	Base-emitter saturation voltage	$I_{C} = 8.0 \text{ A}; I_{B} = 1.6 \text{ A}$ $I_{C} = 5.0 \text{ A}; I_{B} = 1.0 \text{ A}$	-	- 1.0	2.0	V V
h <sub>FE</sub> h <sub>FEsat</sub>	DC current gain	$  I_{C} = 8.0 \text{ A}; I_{B} = 1.6 \text{ A} $ $  I_{C} = 5.0 \text{ A}; V_{CE} = 5 \text{ V} $ $  I_{C} = 8.0 \text{ A}; V_{CE} = 5 \text{ V} $	8 6	1.1 - -	1.6 40 30	V

## **DYNAMIC CHARACTERISTICS**

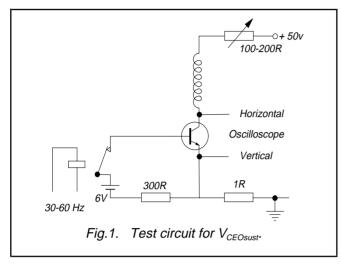
T<sub>mb</sub> = 25 °C unless otherwise specified

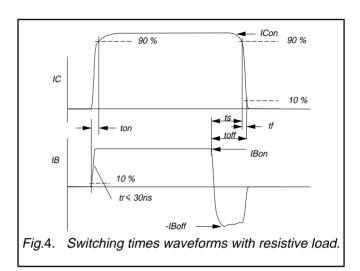
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
	Switching times (resistive load)	$I_{Con} = 5 \text{ A}; I_{Bon} = -I_{Boff} = 1 \text{ A}; $ $R_L = 75 \text{ ohms}; V_{BB2} = 4 \text{ V};$			
t <sub>s</sub> t <sub>f</sub>	Turn-off storage time Turn-off fall time		2.2 0.26	3.3 0.7	μs μs
	Switching times (inductive load)	$I_{Con} = 5 \text{ A}; I_{Bon} = 1 \text{ A}; L_{B} = 1 \mu\text{H}; -V_{BB} = 5 \text{ V}$			
$\mathbf{t_s}$	Turn-off storage time Turn-off fall time		1.35 0.1	2.3 0.5	μs μs
	Switching times (inductive load)	$I_{Con} = 5A$ ; $I_{Bon} = 1 A$ ; $L_{B} = 1 \mu H$ ; - $V_{BB} = 5 V$ ; $T_{i} = 100 ^{\circ} C$			
t <sub>s</sub> t <sub>f</sub>	Turn-off storage time Turn-off fall time	1 100 0 1, 1, 100 0	1 1	3.2 0.9	μs μs

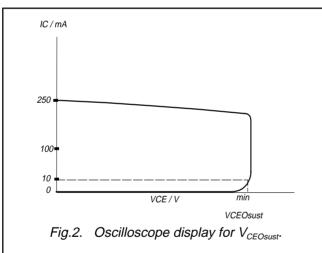
March 2018 2 Rev 1.100

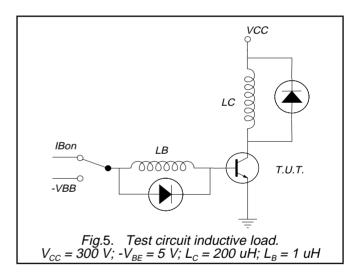
<sup>1</sup> Measured with half sine-wave voltage (curve tracer).

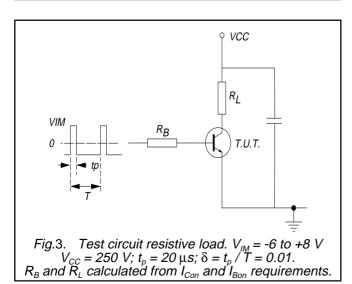
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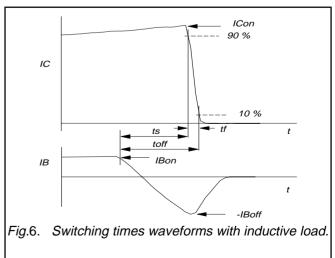




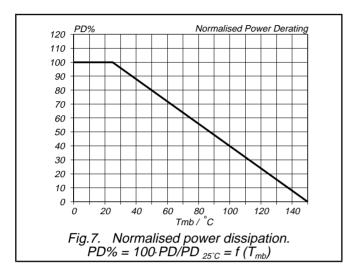


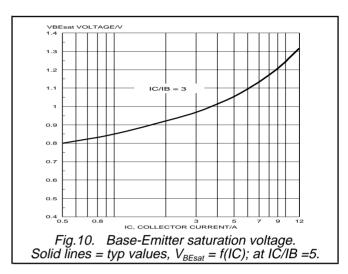


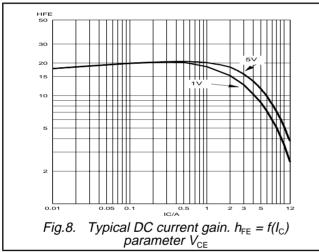


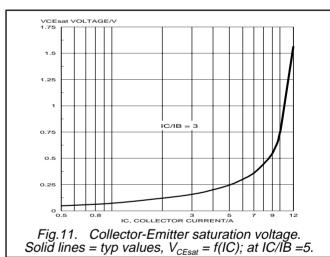


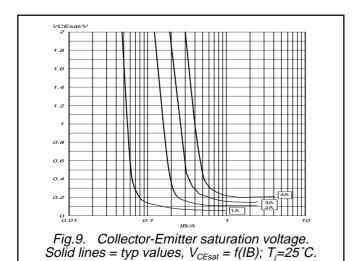
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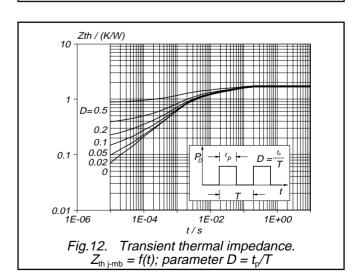




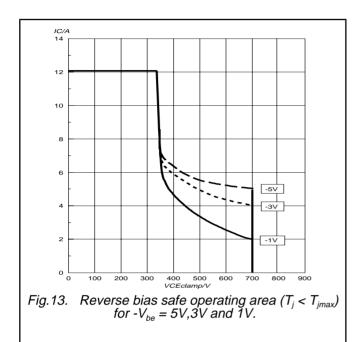


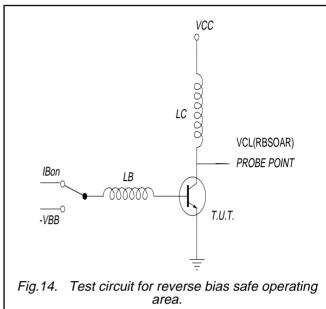






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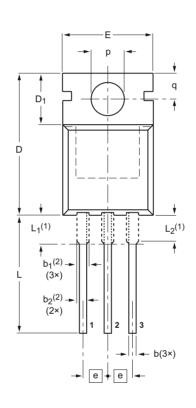
$$\begin{split} V_{clamp} < 700V; \ V_{cc} = 150V; \ -V_{be} = 5V, 3V \ \& \ 1V; \\ L_B = 1 \mu H; \ L_C = 200 \mu H \end{split}$$

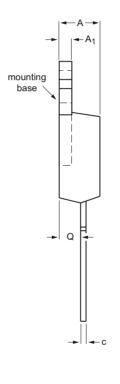
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## **MECHANICAL DATA**

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78





0 5 10 mm scale

#### **DIMENSIONS** (mm are the original dimensions)

UNIT	Α	A <sub>1</sub>	b	b <sub>1</sub> <sup>(2)</sup>	b <sub>2</sub> <sup>(2)</sup>	C	D	D <sub>1</sub>	E	е	L	L <sub>1</sub> <sup>(1)</sup>	L <sub>2</sub> <sup>(1)</sup> max.	р	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

#### Notes

- Lead shoulder designs may vary.
   Dimension includes excess dambar.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DA		
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE	
SOT78		3-lead TO-220AB	SC-46		<del>08-04-23</del> 08-06-13	

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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